2SJ496

Silicon P Channel MOS FET

R07DS0433EJ0400
(Previous: REJ03G0870-0300)
Rev.4.00
Jun 07, 2011

Description

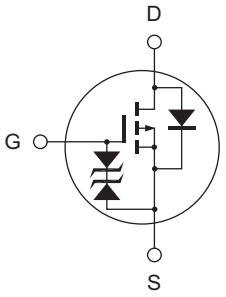
High speed power switching

Features

- Low on-resistance
  $R_{DS\ (on)}$ = 0.12 Ω typ. (at V_{GS} = –10 V, I_D = –2.5 A)
- 4 V gate drive devices.
- Large current capacitance
  I_D = –5 A

Outline

RENESAS Package code: PRSS0003DC-A
(Package name: TO-92 Mod)



1. Source
2. Drain
3. Gate

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Drain to source voltage	V_{DSS}	–60	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I_D	–5	A
Drain peak current	$I_{D\ (pulse)}$ Note 1	–20	A
Body to drain diode reverse drain current	I_{DR}	–5	A
Avalanche current	I_{AP} Note 3	–5	A
Avalanche energy	E_{AR} Note 3	2.14	mJ
Channel dissipation	Pch Note 2	0.9	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	–55 to +150	°C

Notes: 1. PW ≤ 100 μs, duty cycle ≤ 10%
2. Value at Ta = 25°C
3. Value at Tch = 25°C, Rg ≥ 50 Ω

Electrical Characteristics

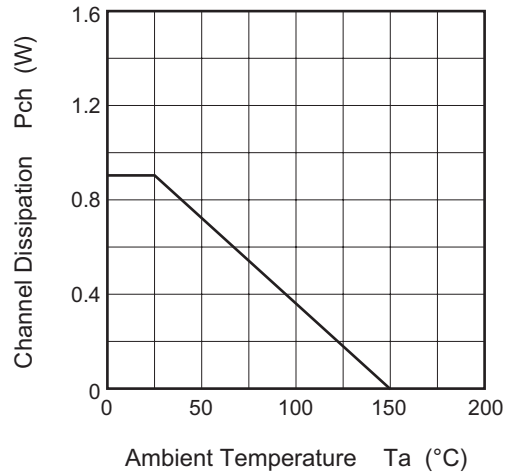
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)\ DSS}$	–60	—	—	V	I_D = –10 mA, V_{GS} = 0
Gate to source breakdown voltage	$V_{(BR)\ GSS}$	±20	—	—	V	I_G = ±100 μA, V_{DS} = 0
Zero gate voltage drain current	I_{DSS}	—	—	–10	μA	V_{DS} = –60 V, V_{GS} = 0
Gate to source leak current	I_{GSS}	—	—	±10	μA	V_{GS} = ±16 V, V_{DS} = 0
Gate to source cutoff voltage	$V_{GS\ (off)}$	–1.0	—	–2.0	V	I_D = –1 mA, V_{DS} = –5 V
Static drain to source on state resistance	$R_{DS\ (on)}$	—	0.12	0.16	Ω	I_D = –2.5 A, V_{GS} = –10 V Note 4
	$R_{DS\ (on)}$	—	0.17	0.24	Ω	I_D = –2.5 A, V_{GS} = –4 V Note 4
Forward transfer admittance	$\|y_{fs}\|$	3	5	—	S	I_D = –2.5 A, V_{DS} = –10 V Note 4
Input capacitance	Ciss	—	600	—	pF	V_{DS} = –10 V
Output capacitance	Coss	—	290	—	pF	V_{GS} = 0
Reverse transfer capacitance	Crss	—	80	—	pF	f = 1 MHz
Turn-on delay time	$t_{d\ (on)}$	—	10	—	ns	V_{GS} = –10 V
Rise time	t_r	—	25	—	ns	I_D = –2.5 A
Turn-off delay time	$t_{d\ (off)}$	—	95	—	ns	R_L = 12 Ω
Fall time	t_f	—	55	—	ns	
Body to drain diode forward voltage	V_{DF}	—	–1.0	—	V	I_F = –5 A, V_{GS} = 0
Body to drain diode reverse recovery time	t_{rr}	—	65	—	ns	I_F = –5 A, V_{GS} = 0 di_F/dt = 50 A/μs

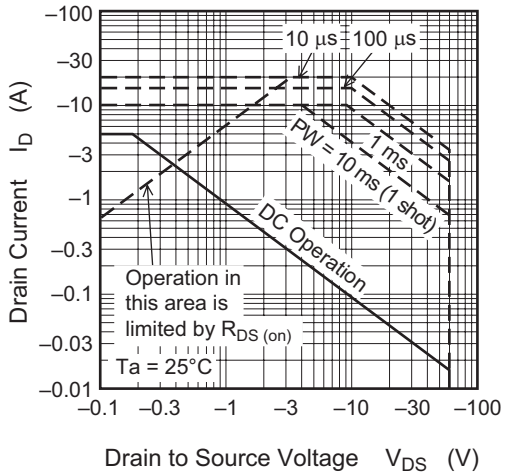
Note: 4. Pulse test

Main Characteristics

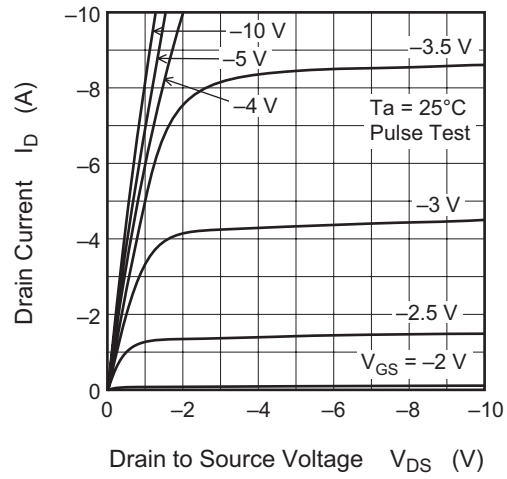
Power vs. Temperature Derating



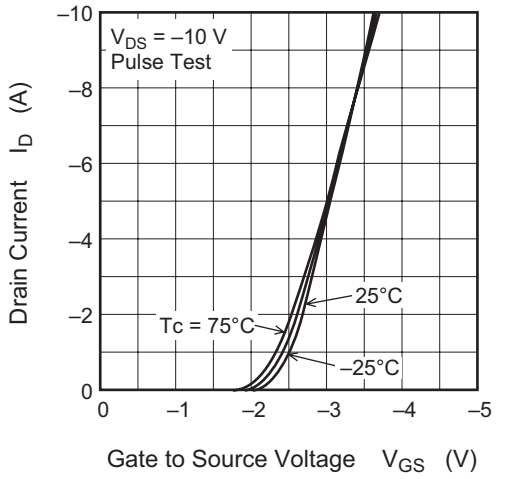
Maximum Safe Operation Area



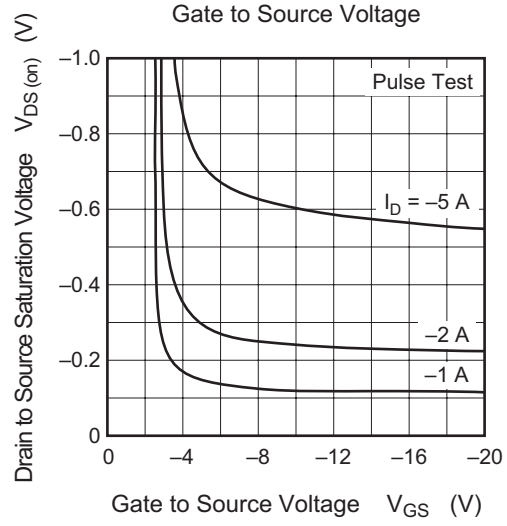
Typical Output Characteristics



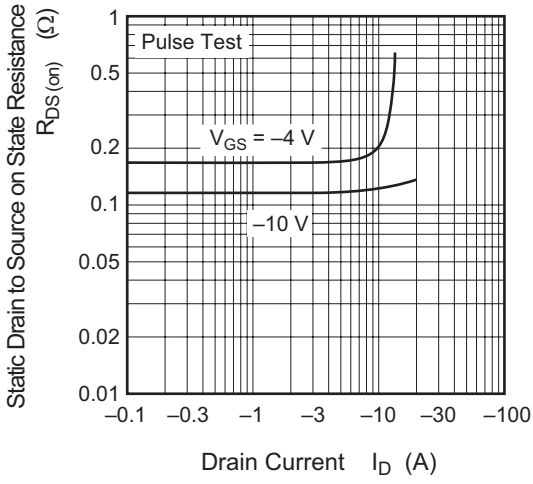
Typical Transfer Characteristics



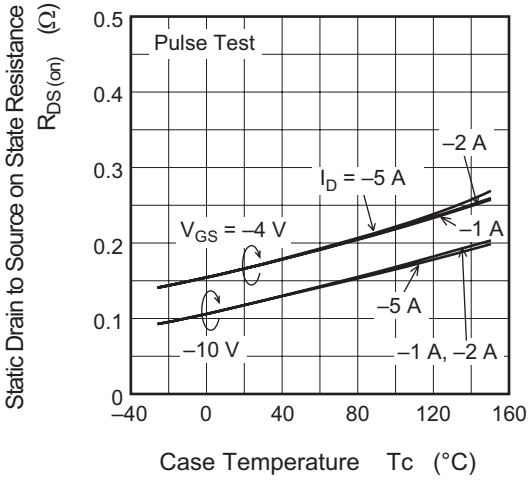
Drain to Source Saturation Voltage vs. Gate to Source Voltage



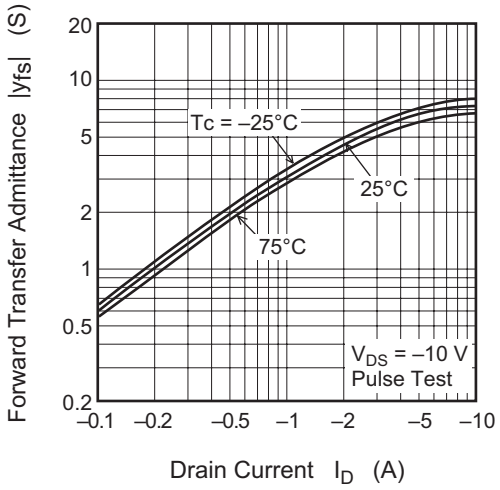
Static Drain to Source on State Resistance vs. Drain Current



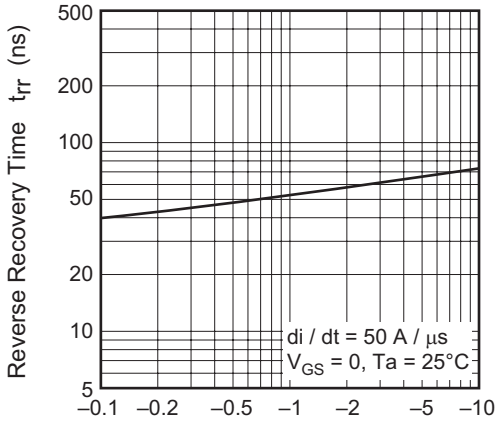
Static Drain to Source on State Resistance vs. Temperature



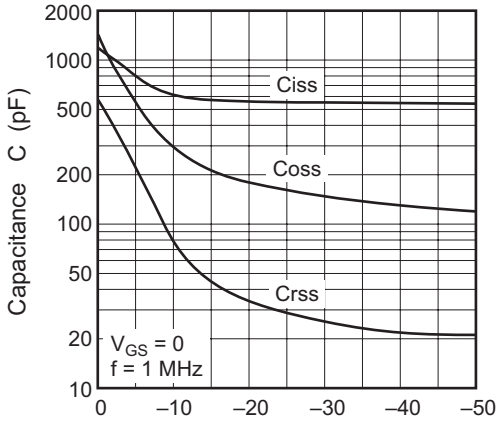
Forward Transfer Admittance vs. Drain Current



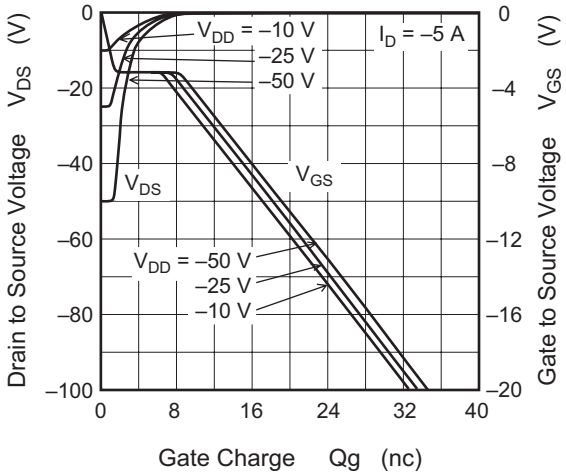
Body-Drain Diode Reverse Recovery Time



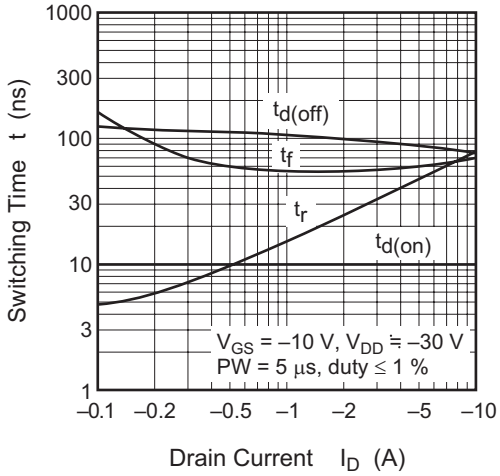
Typical Capacitance vs. Drain to Source Voltage



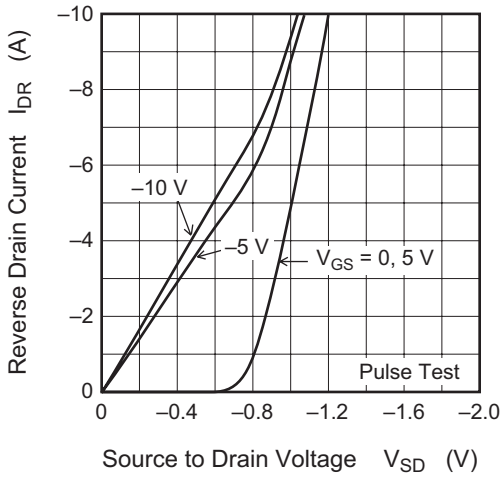
Dynamic Input Characteristics



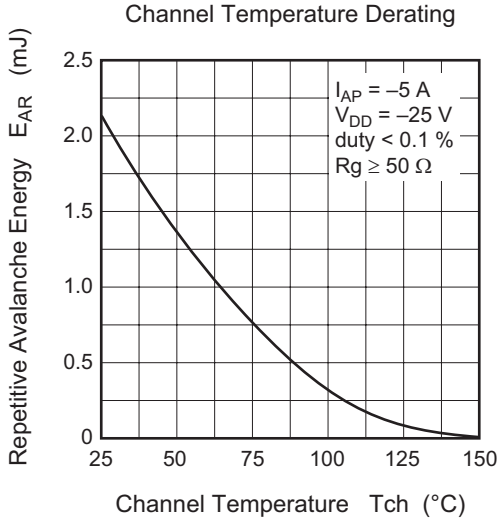
Switching Characteristics



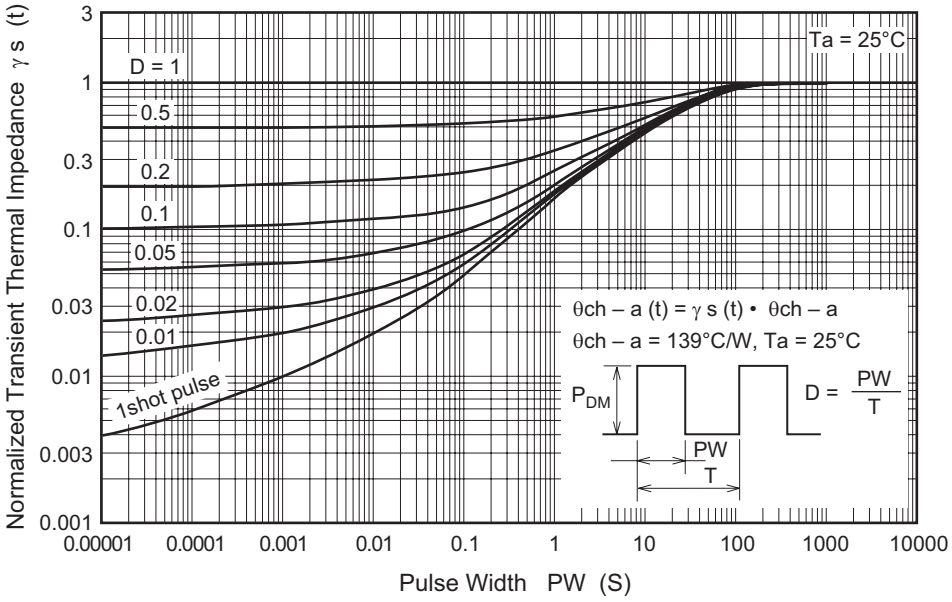
Reverse Drain Current vs. Source to Drain Voltage



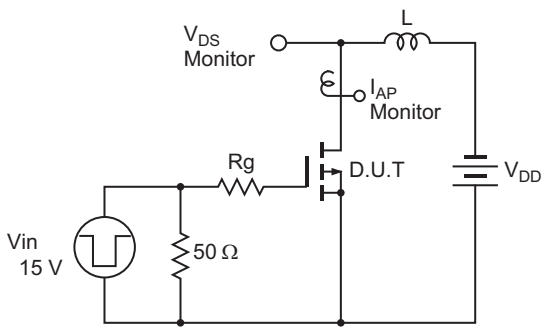
Maximum Avalanche Energy vs. Channel Temperature Derating



Normalized Transient Thermal Impedance vs. Pulse Width

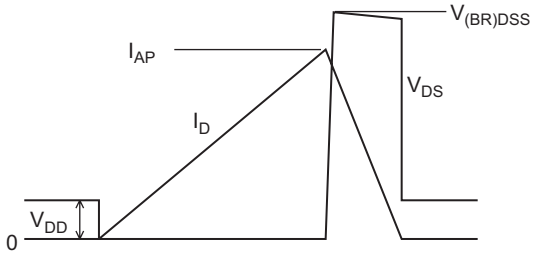


Avalanche Test Circuit

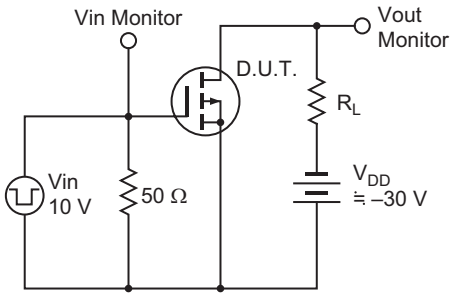


Avalanche Waveform

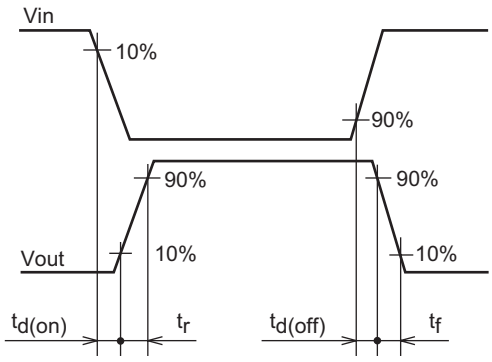
$$E_{AR} = \frac{1}{2} \cdot L \cdot I_{AP}^2 \cdot \frac{V_{DSS}}{V_{DSS} - V_{DD}}$$



Switching Time Test Circuit



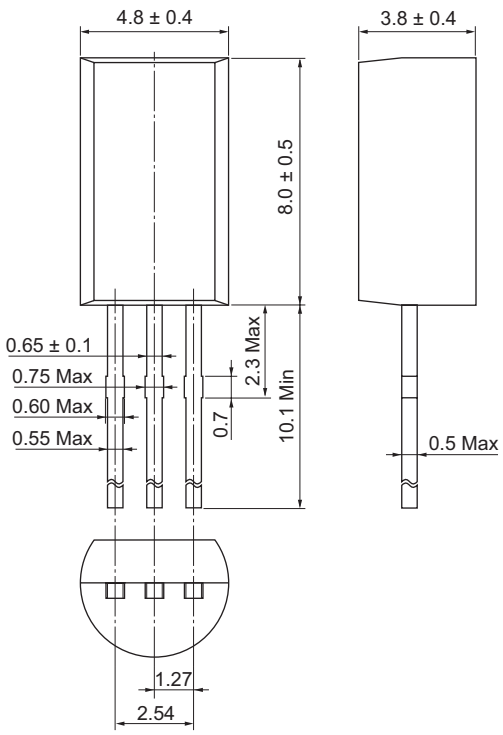
Waveform



Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TO-92 Mod	SC-51	PRSS0003DC-A	TO-92 Mod / TO-92 ModV	0.35g

Unit: mm



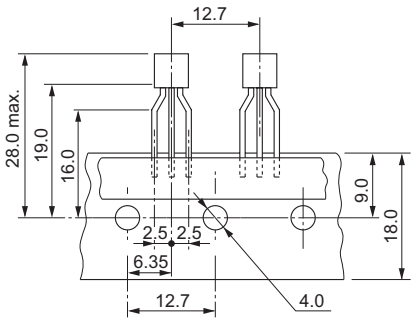
Ordering Information

Part Name	Quantity	Shipping Container
2SJ496TZ-E	2500 pcs	Taping

Notes: 1. For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

2. Leads is forming applied as following figure.

Unit: mm



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Renesas Electronics America Inc.
2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

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